Philips Semiconductors

Product specification

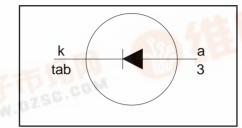
Rectifier diodes Schottky barrier

PBYR725D series

FEATURES

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

$$V_R = 20 \text{ V}/25 \text{ V}$$
 $I_{F(AV)} = 7.5 \text{ A}$
 $V_F \le 0.4 \text{ V}$

GENERAL DESCRIPTION

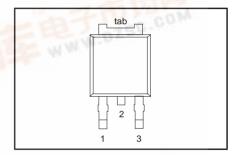
Schottky rectifier diodes intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYR725D series is supplied in the SOT428 surface mounting package.

PINNING

| DESCRIPTION | | |
|----------------------|--|--|
| no connection | | |
| cathode ¹ | | |
| anode | | |
| cathode | | |
| | | |

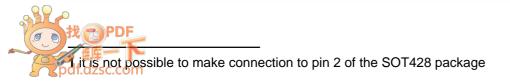
SOT428



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | | UNIT |
|--------------------|---------------------------------------|---|------|---------------|---------------|--------|
| V | Dook ropotitivo rovorgo | PBYR7 | | 20D 20 | 25D 25 | V |
| V_{RRM} | Peak repetitive reverse voltage | | - | 20 | 25 | \ \ |
| V_{RWM} | Working peak reverse voltage | TO THE STATE OF | - | 20 | 25 | V |
| V_R | Continuous reverse voltage | T _{mb} ≤ 119 °C | - | 20 | 25 | V |
| I _{F(AV)} | Average rectified forward current | square wave; $\delta = 0.5$; $T_{mb} \le 138$ °C | - | 7.5 | | А |
| I _{FRM} | Repetitive peak forward current | square wave; $\delta = 0.5$; $T_{mb} \le 138$ °C | - | 1 | 5 | А |
| I _{FSM} | Non-repetitive peak forward current | t = 10 ms t = 8.3 ms sinusoidal; T _j = 125 °C prior to | EE | | 00 10 | A A |
| I _{RRM} | Peak repetitive reverse surge current | surge; with reapplied V _{RRM(max)} pulse width and repetition rate limited by T _{i max} | - | | 1 | А |
| T _j | Operating junction temperature | , in max | - | 15 | 50 | °C |
| T_{stg} | Storage temperature | SC.CO. | - 65 | 17 | 75 | °C |



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THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------------|--|---|------|------|------|------|
| R _{th j-mb} | Thermal resistance junction to mounting base | | 1 | • | 3 | K/W |
| R _{th j-a} | | pcb mounted, minimum footprint, FR4 board | - | 50 | - | K/W |

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified

| | • | | | | | |
|----------------|----------------------|--|------|------|------|------|
| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
| V_{F} | Forward voltage | $I_{\rm F} = 7.5 \text{ A}; T_{\rm i} = 125^{\circ}\text{C}$ | - | 0.33 | 0.4 | V |
| · . | | $I_{\rm F} = 15 \text{A}; T_{\rm i} = 125 ^{\circ} \text{C}$ | - | 0.45 | 0.52 | V |
| | | $I_{\rm F} = 15 \text{A}^{\prime}$ | - | 0.52 | 0.62 | V |
| I _R | Reverse current | $\dot{V}_{R} = V_{RWM}$ | - | 0.2 | 5 | mΑ |
| " | | $V_R = V_{RWM}$; $T_i = 100$ °C | - | 15 | 30 | mΑ |
| C _d | Junction capacitance | $V_R = 5 \text{ V}$; $f = 1 \text{ MHz}$, $T_i = 25 \text{ °C to } 125 \text{ °C}$ | - | 580 | - | pF |

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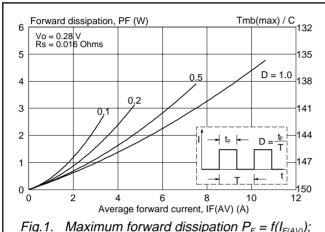
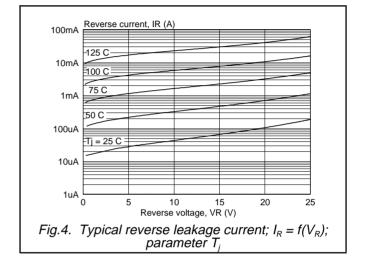


Fig.1. Maximum forward dissipation $P_F = f(I_{F(AV)});$ square current waveform where $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}.$



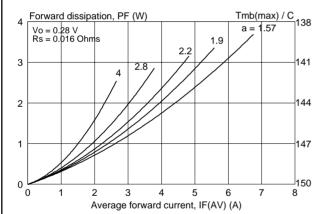


Fig.2. Maximum forward dissipation $P_F = f(I_{F(AV)})$; sinusoidal current waveform where a = f(AV) factor $= I_{F(RMS)} / I_{F(AV)}$.

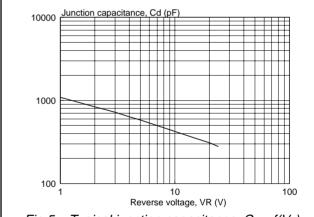


Fig.5. Typical junction capacitance; $C_d = f(V_R)$; f = 1 MHz; $T_j = 25^{\circ}\text{C}$ to 125°C .

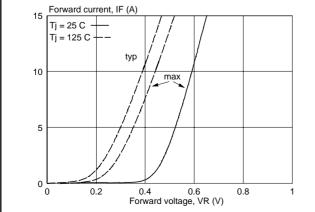


Fig.3. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_i

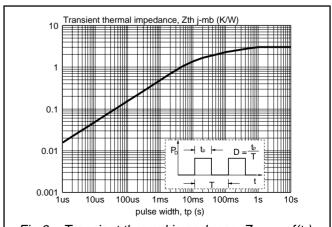
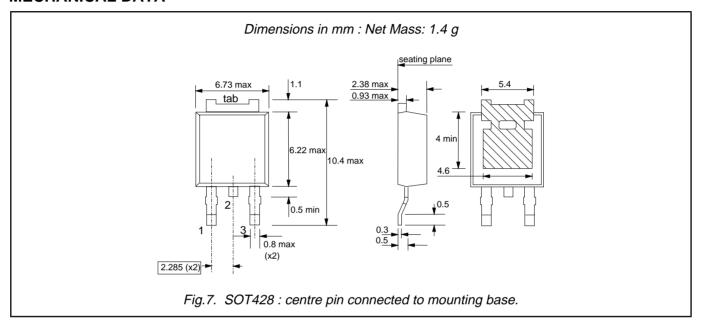


Fig.6. Transient thermal impedance; $Z_{th j-mb} = f(t_p)$.

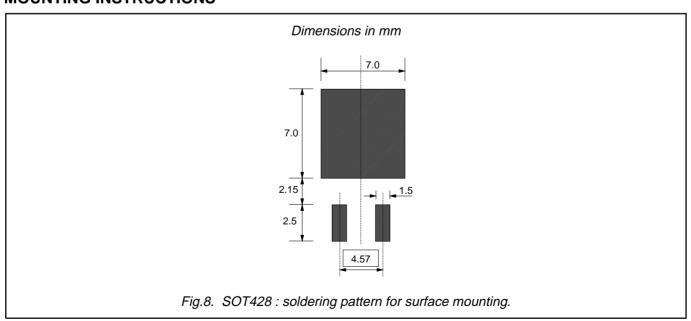
Philips Semiconductors Product specification

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MECHANICAL DATA



MOUNTING INSTRUCTIONS



Notes

- Observe the general handling precautions for electrostatic-discharge sensitive devices (ESDs) to prevent damage to MOS gate oxide.
 Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

| Rectifier | diodes |
|-----------|---------|
| Schottky | barrier |

PBYR725D series

DEFINITIONS

| Data sheet status | | | | |
|---------------------------|---|--|--|--|
| Objective specification | This data sheet contains target or goal specifications for product development. | | | |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. | | | |
| Product specification | This data sheet contains final product specifications. | | | |
| I the Marian and the same | | | | |

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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